Minimal Invasive Beam Profile Monitors for High Intense Hadron Beams

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Basics on physics, recent technical realizations and some applications for:

- Detection of residual gas products: IPM and BIF
- Laser 'wire' and electron beam scanners
- Photon emission for relativistic beams: OTR and SRM

Comparison as a summary

Remark: Examples are presented from different laboratories. An extended list of existing installations is given in the written proceedings.

Profile Measurement Demands

Non-invasive diagnostics \Rightarrow **undisturbed observation of beam parameters**

Transfer line: Observation of same beam at different locations, variation during pulse
 Synchrotron: Observation of variation during acceleration and any further manipulations
 Large beam power: Destruction of intersecting material as wire scanner, screen, SEM-Grid
 Diagnostics with small impact on beam *and* instrument => high sensitivity

Typical beam parameter:

- > Beam width σ : 0.3 mm to 10 mm (sometimes non-Gaussian)
- Beam current I beam: Pulsed LINAC up to 100 mA, synchrotron up to 10 A

Physical basis for detection:

- Electronic Stopping Power dE/dx: Ionization Profile Monitor IPM Beam Induced Fluorescence BIF Monitor
- Photo-detachment for H⁻ beams: Laser 'Wire' Scanner LWS
- Deflection in beam's space charge: Electron Beam Scanner EBS
- Transition radiation for rel. beams E>10 GeV: OTR Screens ('minimal invasive' method)
- Synchrotron radiation for rel. beams E>100 GeV: Synchrotron Radiation Monitor SRM

Signal Strength for IPM and BIF-Monitor

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Ionization Profile Monitor

Main application: Synchrotrons and transfer lines for all beams

GSI

Ionization Profile Monitor: Principle

Advantage: ' 4π -detection scheme' for ionization products **Detection scheme:**

- Secondary e⁻ or ions accelerated by E-field electrodes & side strips E≈ 50... 300 kV/m
- > MCP (Micro Channel Plate) electron converter & 10⁶-fold amplifier
- either Phosphor screen & CCD \rightarrow high **spatial** resolution of 100 μ m
- > or wire array down to 250 μm pitch \rightarrow high **time** resolution





IPMs are installed in nearly all synchrotrons However, no 'standard' realization exists!

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Ionization Profile Monitor: Realization at GSI and FZJ



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Ionization Profile Monitor: Realization at GSI and FZJ

Insertion 650 mm **Example:** Installation at GSI and FZJ **IPM** support \blacktriangleright Electric potential ±6 kV \Rightarrow E=70 kV/m & UV lamp electrodes \Rightarrow 1% homogeneity Ø250 mm ➤MCP for single particle detection & Horizontal IPM: **Vertical IPM** phosphor for light spot, 100x50 mm² **E-field box** ➢ Readout by camera with 200 fps **Electrodes** ►UV lamp: beam calibration of MCP sensitivity MCH -0000m E-field separation disks View port Ø150 mm Horizontal camera

Installation at FZJ-COSY: insertion 650mm

C. Böhme (FZJ), T Giacomini (GSI) et al, DIPAC'09

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IPM: Observation of Cooling and Stacking

Example:

U⁷³⁺ beam at GSI for intensity increase stacking by *electron cooling* and acc. 11.4 \rightarrow 400 MeV/u

IPM: Profile recording every 10 ms measurement within *one* cycle.



Task for IPM:

- Observation of cooling
- Emittance evaluation during cycle

see poster: V. Kamerdzhiev (FZJ) et al., MOPD093 P. Forck (GSI) et al., DIPAC'05

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IPM: Turn-by-Turn Measurement

Important application:

Injection matching

to prevent for emittance enlargement \Rightarrow turn-by-turn measurement Required time resolution 100 ns **Example**: Injection to J-PARC RCS at 0.4 GeV Anode: wire array with 1mm pitch



Further advanced turn-by-turn IPMs at BNL, CERN, FNAL etc.

H. Hotchi (J-PARC), HB'08, A Satou (J-PARC) et al., EPAC'08

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IPM: Space Charge Influence for Intense Beams



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IPM: Magnet Design



Design by G. de Villiers (iThemba Lab), T. Giacomini (GSI) Further types of magnets e.g. K.Satou (J-PARC) et al., EPAC'08, J.Zagel (FNAL) et al., PAC'01, R.Connolly (RHIC) et al., PAC'01, C. Fischer (CERN) et al. BIW'04



Beam Induced Fluorescence Monitor

Main application: Transfer lines for all beams

Beam Induced Fluorescence Monitor: Principle

Detecting *photons* from residual gas molecules, e.g. Nitrogen N_2 + Ion $\rightarrow (N_2^+)^*$ + Ion $\rightarrow N_2^+ + \gamma$ + Ion N₂-fluorescent gas emitted into solid angle Ω to camera $\sqrt{a^{cuum}}$ equally distributed Blackened walls 150mm flange Valve ViewPort ens, Image-Intensifier and CCD FireWire-Camera

F. Becker (2007) et al., Proc. DIPAC'07



Beam Induced Fluorescence Monitor: Principle

Detecting *photons* from residual gas molecules, e.g. Nitrogen N_2 + Ion $\rightarrow (N_2^+)^*$ + Ion $\rightarrow N_2^+ + \gamma$ + Ion emitted into solid angle Ω to camera $\sqrt{a^{cuum}}$ 150mm flange

Features:

- Single pulse observation possible down to $\approx 10 \ \mu s$ time resolution
- High resolution (here 0.2 mm/pixel) can be matched to application
- Commercial Image Intensifier
- Less installations inside vacuum as for IPM

See poster Y. Hashimoto (J-PARC) et al., MOPE014

F. Becker (2007) et al., Proc. DIPAC'07

ຊຸຊຸຊຸຊຸດ ວິ aver. pixel int. Beam: $4x10^{10}$ Xe $^{48+}$ at 200MeV/u, p=10⁻³ mbar 14 Minimal Invasive Profile Monitors for Hadron Beams

beam direction

Blackened walls

Viewport

iewport size

N₂-fluorescent gas equally distributed

profile

Valve

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BIF-Monitor: Technical Realization

Example BIF station at GSI-LINAC:

- Insertion length 25 cm
- 2 x image intensified CCD cameras
- Optics with reproduction scale 0.2 mm/pixel
- Gas inlet + gauge
- Pneumatic feed-through for calibration

Realization at other labs (e.g.BNL, CERN, FZJ): Segmented photomultiplier, CID or emCCD







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BIF-Monitor: Signal Scaling

Scaling of fluorescence yield:

Experiments at CERN-synchrotrons and GSI HEBT behind synchrotron \Rightarrow yield scales like Bethe-Bloch equation

Further results:

- Excited transitions independent of energy
- Fluorescence yield proportional to vacuum pressure
- Profile width independent of pressure tested for 10⁻⁶ to 10⁻¹ mbar
- ➤ Lifetime independent on energy ≈60 ns for N₂ and ≈6 ns for Xe

Example: CERN-PS for p in N₂ and Xe



M. Plum (LANL&CERN) et al., NIM A (2002), F. Becker (GSI) et al, Proc DIPAC'07

BIF-Monitor: Spectroscopy – Fluorescence Yield



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BIF-Monitor: Spectroscopy – Profile Reading



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Laser 'Wire' Scanner

Main application: Transfer lines H⁻ beams only

Laser Scanner: Principle for H⁻ Beams

Photo-detachment: $H^- + \gamma \rightarrow H^0 + e^-$ binding energy $E=0.75 \text{ eV} \leftrightarrow \lambda=1670 \text{ nm}$

Photo-detachment maximal at λ =830 nm Doppler shifted photon energy in rest-frame:



Y. Liu (SNS) et al., NIM A 238, 241 (2010) , R.Connolly et al., Proc. LINAC'02

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Lab frame laser wavelength

Laser Scanner: Detection Scheme for H⁻ at SNS-LINAC

SNS installation:

Nd:YAG (50-200 mJ, 7ns) in laser room ≻One of 9 stations is served at a time ≻Laser with spot size: 10 to 50 µm



Y. Liu (SNS) et al., NIM A 238, 241 (2010),D.A. Lee (RAL) et al., EPAC '08,R. Connolly (BNL) et al. BIW'10

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Laser Scanner: Detection Scheme for H⁻ at SNS-LINAC

SNS installation:

Nd:YAG (50-200 mJ, 7ns) in laser room
>One of 9 stations is served at a time
>Laser with spot size: 10 to 50 μm
>e⁻ separation by B≈20 mT (β-dependent)
>Detection with Faraday Cup



Electron collector

Dipole magnet

Y. Liu (SNS) et al., NIM A 238, 241 (2010),D.A. Lee (RAL) et al., EPAC '08,R. Connolly (BNL) et al. BIW'10

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Laser Scanner: Results for H⁻ at SNS-LINAC

SNS installation:

Nd:YAG (50-200 mJ, 7ns) in laser room
>One of 9 stations is served at a time
>Laser with spot size: 10 to 50 μm
>e⁻ separation by B≈20 mT (β-dependent)
>Detection with Faraday Cup
>Example: Profile measurement at SNS
>Advantage: Time resolution ≈30 ns

 \Rightarrow variation during macro-pulse

Compact installation with local laser possible
 Spatial resolved detection of separated H⁰
 → emittance determination

Long. bunch shape measurement possible
Applicability considered for 70 keV at RAL

Y. Liu (SNS) et al., NIM **A** 238, 241 (2010),

D.A. Lee (RAL) et al., EPAC '08,

R. Connolly (BNL) et al. BIW'10, J. Pogge (SNS) et al., Proc. BIW '08





Electron Beam Scanner

Main application: Synchrotrons for all beams

Electron Beam Scanner: Principle



Electron Beam Scanner: Installation at SNS-Ring

Installation for horizontal profile

Phosphor Parameter for SNS: & camera ≻Total length: 1.5 m Electron energy: max. 75 keV Electron current: max. 5 mA ► Repetition rate: 5 Hz Phosphor observation with camera Scan duration: 20 ns

Requirements:

➢Optimal electron energy depends on ion current ➤Shielding against

external B-fields

beam pipe Ø250mm

protons

quadrupoles

rf deflector

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electron gun Scanner Design: BINP, Novosibirsk

W. Blokland (SNS) et al., Proc. DIPAC'09

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Electron Beam Scanner: Results

Example:

Raw data: horizontal defection for 5 μ C at SNS Ring



 Device tested with 7.7 keV/u K⁺ P.K. Roy (LBNL) et al. (2005)
 Ion beam scanner tested with p at 50 MeV and 150-450 GeV J. Bosser (CERN) et al., (2002)

W. Blokland (SNS) et al., Proc. DIPAC'09

Sliced profile:

Proton beam 4 µC filling 20 ns scan one bunch at a turn 343 (recorded at consecutive ring fillings)



Advantage:

Sliced profile recording with 20 ns resolution!



Optical Transition Radiation Screen

Main application: Synchrotrons and Transfer lines for E > 10 GeV

Optical Transition Radiation Monitor: Principle

Physics: Boundary with different dielectric constant → Emission of photons within cone centered at 1/γmaximum scaling $dN/dθ \propto γ^2$ Practical usage only for E > 10 GeV Surface phenomena \Rightarrow thin foil possible



OTR screens operational at FNAL, CERN, J-PARC...

OTR-Monitor: Technical Realization

Physics: Boundary with different dielectric constant

→ Emission of photons within cone centered at $1/\gamma$ maximum scaling $dN/d\theta \propto \gamma^2$ Practical usage only for E > 10 GeV Surface phenomena \Rightarrow thin foil possible

Example of realization at TERATRON:

➢Insertion of foil

e.g. 5 µm Kapton coated with 0.1µm Al
 ➢ Invasive diagnostics but thin foil allows for observation of several turns

>Advantage:

thin foil \Rightarrow low heating & low straggling 2-dim image visible

Installation at FNAL-TEVATRON



V.E. Scarpine (FNAL) et al., BIW'06

OTR-Monitor: Results

Physics: Boundary with different dielectric constant

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Measurement at FNAL-TEVATRON



Example of results: Single proton bunch at 150 GeV with turn-by-turn resolution

2-dim image: x-y coubling visible e.g. effect on e.g. skew quadupoles

V.E. Scarpine (FNAL) et al., BIW'06

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OTR-Monitor: Results

Example for target diagnostics at FNAL:

Insertion of OTR in front of NuMI target 120-150 GeV protons for neutrino physics Online profile observation possible

Radiation hardness test at FNAL:

7.10¹⁹ protons in 70 days → half signal strength but *same* width reading

Application: Target \rightarrow online diagnosticsSynchrotron \rightarrow injection studies

Further studies: Coherent OTR Optical Diffraction Radiation



V.E. Scarpine (FNAL) et al., PAC'07

Time (days)



Synchrotron Radiation Monitor

Main application: Synchrotrons for E > 100 GeV

Synchrotron Radiation Monitor: Principle

Physics: Emission of radiation by charges on bent trajectory



H.W.K. Cheung (FNAL) et al., PAC'03, R. Thruman-Keup (FNAL), BIW'06, G. Kube (DESY) et al., BIW'06

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Synchrotron Radiation Monitor: Technical Realization

Physics: Emission of radiation by charges on bent trajectory



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Synchrotron Radiation Monitor: Results

Physics: Emission of radiation by charges on bent trajectory

For a dipole: $P \propto \frac{\gamma^4}{\rho^2}$ and $\lambda_c \propto \frac{\rho}{\gamma^3}$

Dipole of p = 1km, y=1000 ⇒ λ_c≈ 4µm
Radiation from dipole-fringe field: shorter λ_c
Undulator for 100 to 500 GeV

Example for realization at Tevatron:

Optical table with intensified CID *Example* for realization at LHC:

- > Undulator 0.45 \rightarrow 1.2 TeV,
- ➢ Dipole edge: 1.2→3 TeV
- Dipole center 3 to 7 TeV

Example from LHC acceleration:

➢Radiation from undulator for 0.45 TeV

- ➢Online display every 20 ms
- ➤Turn-by-turn readout in preparation

T. Lefevre (CERN) et al., IPAC'10, R. Jones (CERN), BIW'10



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Comparison of minimal invasive Profile Diagnostics

Very simplified comparison between the minimal invasive methods

	IPM	BIF	EBS	LWS	OTR	SRM
Physics	Energy loss	Energy loss	Space charge defl.	Photo- detachment	Transition radiation	Sycnhrotron light
Beam precaution	None	None	None	H.	<i>E</i> >10 GeV	<i>E</i> >100 GeV
Profile display	Projection	Projection	Projection	Projection	2-dim	2-dim
Imaging meth.	Continuous	Continuous	Scan 10 Hz	Scan 30 Hz	Continuous	Continuous
Signal strength	Medium	Low	High	High	Medium	Low
Time resolution	100 ns	1 μs	10 ns	10 ns	1 μs	10 μs
Spatial resolution	100 µm	30 µm	100 µm	30 µm	10 µm	100 μm
Complexity	High	Low	Medium	High	Low	Very high
Main application	Synchr. & Trans. line	Trans. line	Synchr.	Trans.line	Synchr.& Trans. Line	Synchr. only

Negative ion beam sheet: see poster K. Shinto (JAEA) et al., MOPE016

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